National Semiconductor

LM342 Series 3-Terminal Positive Regulators

General Description

The LM342-XX series of three-terminal regulators is available with several fixed output voltages, making them useful in a wide range of applications. One of these is local on card regulation, eliminating the distribution problems associated with single point regulation. The voltages available allow these regulators to be used in logic systems, instrumentation, HiFi, and other solid state electronic equipment. Although designed primarily as fixed voltage regulators these devices can be used with external components to obtain adjustable voltages and currents.

The LM342-XX series is available in the plastic TO-202 package. This package allows these regulators to deliver over 0.25A if adequate heat sinking is provided. Current limiting is included to limit the peak output current to a safe value. Safe area protection for the output transistor is provided to limit internal power dissipation. If internal power dissipation becomes too high for the heat sinking provided, the thermal shutdown circuit takes over, preventing the IC from overheating.

Considerable effort was expended to make the LM342-XX series of regulators easy to use and minimize the number of external components. It is not necessary to bypass the

output, although this does improve transient response. Input bypassing is needed only if the regulator is located far from the filter capacitor of the power supply.

For output voltage other than 5V, 12V and 15V the LM117 series provides an output voltage range from 1.2V to 57V.

Features

- Output current in excess of 0.25A
- Internal thermal overload protection
- No external components required
- Output transistor safe area protection
- Internal short circuit current limit
- Available in plastic TO-202 package
- Special circultry allows start-up even if output is pulled to negative voltage (±supplies)

Voltage Range

LM342-5.0 5V LM342-12 12V LM342-15 15V



Schematic Diagram

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications. Maximum Junction Temperature125°CStorage Temperature Range-65°C to +150°CLead Temperature (Soldering, 10 sec.)300°CESD SusceptibilityTBD

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Input Voltage	
$V_0 = 5V$	30V
$V_0 = 12V$ and 15V	35V
Internal Power Dissipation	Internally Limited
Operating Temperature Range	0°C to +70°C

Electrical Characteristics $T_A = 0^{\circ}C$ to $+70^{\circ}C$, $I_O = 250$ mA (Note 2) unless noted

Output Voltage Input Voltage (unless otherwise noted)		5V 10V		12V 19V			15V 23V			Units		
											Symbol	Parameter
Vo	Output Voltage	T _J = 25°C	4.8	5	5.2	11.5	12	12.5	14.4	15	15.6	v
	(Note 3)	1 mA \leq I _O \leq 250 mA and V _{MIN} \leq V _{IN} \leq V _{MAX}	4.75 (7.5	≤V _{IN} :	5.25 ≤20)		≤V _{IN}	12.6 ≤27)	14.25 (18:	≤V _{IN} ≤	15.75 ≤30)	v
ΔV _O	Line Regulation	T _J = 25°C, I _O = 250 mA	(7.3	≤V _{IN} :	55 ≤25)	(14.6	≤VIN	100 ≤30)	(17.7	′≤V _{IN}	100 ≤30)	mV
ΔVO	Load Regulation	$T_{ m J}$ = 25°C, 1 mA \leq I $_{ m O}$ \leq 250 mA			50			120			150	mV
ΔVO	Long Term Stability			20			48			60		mV/khrs
la	Quiescent Current	$T_J = 25^{\circ}C$			6			6			6	mA
ΔlQ	Quiescent Current	$T_{J} = 25^{\circ}C$, 1 mA $\leq I_{O} \leq 250$ mA			0.5			0.5			0.5	mA
	Change	$T_{J} = 25^{\circ}C, V_{MIN} \le V_{IN} \le V_{MAX}$	(7.3	≤VIN	1.5 ≤25)	(14.6	≤V _{IN}	1.5 ≤30)	(17.7	′≤V _{IN}	1.5 ≤30)	mA
Vn	Output Noise Voltage	T _J = 25°C, f = 10 Hz–10 kHz		40			96			120		μV
$\frac{\Delta V_{\text{IN}}}{\Delta V_{\text{OUT}}}$	Ripple Rejection	f = 120 Hz	50	64	×	44	56		42	56		dB
	Input Voltage Required to Maintain Line Regulation	T _J = 25°C, I _O = 250 mA	7.3		÷	14.6			17.7			v
	Thermal Resistance Junction to Case	P Package		15			15			15		°C/W
	Thermal Resistance Junction to Ambient	P Package		80			80			80		°C/W

Note 1: Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the Electrical Characteristics. Note 2: The electrical characteristics data represent pulse test conditions with junction temperatures as shown at the initiation of tests.

Note 3: The temperature coefficient of VOUT is typically within 0.01% VO/°C.

Typical Performance Characteristics









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LM342 Series